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Application Number	<del>Unassigned</del> 19/627,228
Filing Date	Filed Herewith
First Named Inventor	Moghadam, Farhad K., et. al.
Art Unit	<del>Unassigned</del> 1753
Examiner Name	<del>Unassigned</del> VerJeg
Attorney Docket Number	A7632/T49100

**(use as many sheets as necessary)**

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FOREIGN PATENT DOCUMENTS								
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date MM-DD-YYYY	Class Name of Patent or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>o</sup>
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)				
SHV	AM	WO	01/40541	A1	06-07-2001	C23C	16/40	<input type="checkbox"/>
SHV	AN	WO	00/61833	A1	10-19-2000	C23C	16/50	<input type="checkbox"/>
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SHV	AP	WO	00/54320	A1	09-14-2000	H01L	21/44	<input type="checkbox"/>
SHV	AQ	EP	526 779	B1	02-10-1993	C23C	16/04	<input type="checkbox"/>
SHV	AR	EP	442 490	A1	08-21-1991	C30A	25/02	<input type="checkbox"/>
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Examiner Signature		Date Considered	March 31, 2005
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STATEMENT BY APPLICANT**

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of

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Examiner Name	Unassigned VerSteg
Attorney Docket Number	A7632/T49100

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
SHV	AS	"Atomic Layer Deposition" by Physical Inorganic Chemistry, Institute of Applied Synthetic Chemistry, downloaded from website <a href="http://www.ias.tuwien.ac.at/research/fghh/research/pic_research_ald.html">http://www.ias.tuwien.ac.at/research/fghh/research/pic_research_ald.html</a> on 7/23/02	
SHV	AT	GEORGE et al., "Atomic layer controlled deposition of SiO <sub>2</sub> and Al <sub>2</sub> O <sub>3</sub> using ABAB... binary reaction sequence chemistry," <i>Applied Surface Science</i> , 82/83:460-467 (1994).	
SHV	AU	GEORGE et al., "Surface Chemistry for Atomic Layer Growth," <i>J. Phys. Chem.</i> , 100(31):13121-13131 (1996).	
SHV	AV	KLAUS et al., "Atomic Layer Deposition of SiO <sub>2</sub> Using Catalyzed and Uncatalyzed Self-Limiting Surface Reactions," <i>Surface Review and Letters</i> , 6(3/4):435-448 (1999).	
SHV	AW	KLAUS et al., "Atomic layer controlled growth of SiO <sub>2</sub> films using binary reaction sequence chemistry," <i>Appl. Phys. Lett.</i> , 70(9):1092-1094 (1997).	
SHV	AX	MORISHITA et al., "New substances for atomic-layer deposition of silicon dioxide," <i>J. Non-Crystalline Solids</i> , 187:66-69 (1995).	
SHV	AY	WISE et al., "Diethyldiethoxysilane as a New Precursor for SiO <sub>2</sub> Growth on Silicon," from <i>Gas-Phase and Surface Chemistry in electronic Materials Processing</i> , Mountziaris et al., eds., from Symposium held 11/29/93 thru 12/2/93 in Boston Massachusetts, pages 37-43.	
SHV	AZ	YAMAGUCHI et al., "Atomic-layer chemical-vapor-deposition of silicon dioxide films with an extremely low hydrogen content," <i>Applied Surface Science</i> , 130-132:202-207 (1998).	

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